Isolation of a Ferroelectric Intermediate Phase in Antiferroelectric Dense Sodium Niobate Ceramics

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Abstract

Switchable ferroelectric/antiferroelectric ceramics are of significant interest for high power energy storage applications. Grain size control of this switching is an interesting approach to controlling polarization and hence dielectric properties. However, the use of this approach in technologically relevant ceramics is hindered by difficulty in fabricating dense ceramics with small grain sizes. Here an intermediate polar ferroelectric phase (P21ma) has been isolated in dense bulk sodium niobate ceramics by grain size control through spark plasma sintering methods. Our findings, supported by XRD, DSC, P-E (I-E) loops and dielectric characterization, provide evidence that the phase transition from the antiferroelectric (AFE) R-phase, in space group Pnmm, above 300 °C, to the AFE P-phase, in space group Pbma, at room temperature, always involves the polar intermediate P21ma phase and that the P21ma → Pbma transition can be suppressed by reducing grain size.

Graphical abstract

Keywords: Sodium niobate, ceramics, phase transitions, dielectric measurements, grain size.
1. Introduction

The change in polarization that occurs on ferroelectric (FE)/antiferroelectric (AFE) switching in dielectric materials allows for important technical applications such as transducers, sensors, solid-state memories and capacitors [1–4]. The nature, scale and order of the associated phase transition is governed by many factors such as phonons, microstructure, defects and compositional homogeneity [5]. Of these, microstructure is particularly interesting and has been studied and manipulated in many systems such as BaTiO$_3$, Pb(Zr,Ti)O$_3$ and Sr$_2$Bi$_4$Ti$_5$O$_{18}$ [6–9]. For example, decreasing grain size in BaTiO$_3$ leads to the suppression of tetragonal order in the crystal structure and the preservation of the paraelectric cubic phase to room temperature. The suppression of the cubic to tetragonal phase transition is attributed to the containment of single domains within single grains and the limiting of domain growth by the grain boundaries.

Sodium niobate (NaNbO$_3$) is an important lead-free AFE material and its derivatives such as calcium and strontium doped sodium niobate [10–13] and potassium substituted sodium niobate (Na$_{1-x}$K$_x$NbO$_3$) [14–16], have shown great potential in high power energy storage and piezoelectric applications, respectively. NaNbO$_3$ is particularly interesting, as it displays a rich variety of seven phases over the temperature range 173 K to 913 K [17]. NaNbO$_3$ was originally identified by Barth, in 1925, as a cubic perovskite ($a = 3.906$ Å), using X-ray powder diffraction [18]. Later work found the room temperature structure (P-phase) to be orthorhombically distorted in space group $P2_22_1$ ($a = 5.504$ Å, $b = 5.568$ Å, $c = 15.52$ Å) [19], while variable temperature studies suggested a monoclinic distortion at room temperature in space group $P2/m$ ($a = 3.9114$ Å, $b = 3.8813$ Å, $c = 3.9114$ Å, $\beta = 90.67^\circ$) [20]. The structure first presented in 1969 by Sakowski-Cowley et al. [21] in space group Pbma ($a = 5.506$ Å, $b = 5.566$ Å, $c = 15.52$ Å) is now accepted as correctly describing the room temperature structure. Evidence, from high-resolution powder neutron diffraction, suggested a small monoclinic distortion away from true orthorhombic symmetry ($a = 5.5101$ Å, $b = 5.5717$ Å, $c = 15.5181$ Å, $\gamma = 89.94^\circ$) [22,23], but it was later found that this distortion was associated with a room temperature polar phase approximating to orthorhombic symmetry in space group $P2_1ma$ ($a = 5.571$ Å, $b = 7.766$ Å, $c = 5.513$ Å), which can coexist with the non-polar phase (Pbma) [24]. First-principles calculations confirm similar free energies for the polar ($P2_1ma$) and non-polar (Pbma) phases in NaNbO$_3$ [25]. Cross and Nicholson found a double polarization-electric field (P–E) hysteresis loop in a NaNbO$_3$ single crystal at a field of ca. 10 kV mm$^{-1}$ and proposed a field induced transition from antiferroelectric (non-polar) to a ferroelectric (polar) phase.
This was confirmed by Shuvaeva et al. who showed by single crystal X-ray
diffraction a field induced change from $Pbma$ (AFE) to $P2_1ma$ (FE) symmetry [27].
Under high electric field, Ulinzheyev et al. found another field induced phase transition
from orthorhombic to tetragonal through measurements of birefringence in single
crystals [28].

$NaNbO_3$ powder exhibits a crystallographic particle size effect, with micron, sub-
micron and nano sized powders of $NaNbO_3$ exhibiting $Pbcm$, $Pmc2_1$ and $Pmmn$
structures, respectively [29,30]. While this is an interesting phenomenon, its
technological relevance is limited unless these structures can be stabilized in ceramics,
in which case they would be expected to exhibit different polarization behavior.
Obtaining dense ceramics with small grain sizes through conventional sintering is
technically challenging, due to the significant grain growth that occurs at high
temperatures. Recently, ferroelectric behaviour has been reported in nano-grain sized
$NaNbO_3$ ceramics [31], which is inconsistent with the non-polar structure observed in
nano sized powders [29]. Moreover, it has been reported that depending on processing
conditions large grain sized ceramics may exhibit the polar structure [32]. In order to
clarify the physical mechanism of the size effect in $NaNbO_3$ ceramics, in this work,
spark plasma sintering (SPS) is used to prepare ceramics of $NaNbO_3$ with sub-micron
and nano- sized grains, which are compared to micron grain-sized ceramics prepared
by conventional sintering. The phase and polarization behaviors in these ceramics are
examined and reveal new evidence about the nature of the $Pnmm$ to $Pbma$ phase
transition. The transition between these AFE phases appears to be indirect, involving
the $P2_1ma$ FE phase as an intermediate, which can be stabilized through grain size
control. Both structure and polarization behavior are shown to be grain size dependent.

2. Experimental

$NaNbO_3$ samples with micron and sub-micron sized grains were first prepared
through solid state synthesis and then sintered in either a conventional box furnace or
using SPS. Stoichiometric amounts of the starting materials $Na_2CO_3$ (Alfa Aesar,
99.5%, pre-heated at 200 °C for 24 h) and $Nb_2O_5$ (Alfa Aesar, 99.9%) were ground in
ethanol in a nylon container, with zirconia balls, using a planetary ball mill (QM-3SP4,
Nanjing University Instrument Plant, China) for 4 h at 360 rpm. The resulting slurry was
dried and sieved (250 μm). The powder was then calcined at 1000 °C for 2 h in an
alumina crucible. After calcination, the powders were ball milled again for 4 h at 360
rpm in ethanol, dried and sieved. The powder was then pressed uniaxially into pellets
of 10 mm diameter and ca. 1 mm thickness at a pressure of 150 MPa. Pellets were sintered at 1200 °C for 3 h and then slow cooled to form micron grain sized NaNbO₃. Sub-micron grain sized NaNbO₃ was prepared by SPS (HPD 25/1, FCT, Rauenstein, Germany) at 950 °C for 5 min at a uniaxial pressure of 60 MPa. Samples were pressed in a 20 mm diameter graphite die surrounded by carbon foil and pressing carried out under vacuum. Samples of nano-grain sized NaNbO₃ were synthesized via a sol-gel method. Ammonium niobate oxalate hydrate (C₄H₄NNbO₉·xH₂O, 18.5 g, Aldrich, 99.99%) and NaNO₃ (5.2 g, Hopkin & Williams, 99%) were separately dissolved in 5 ml of distilled water. Gelatine (15 g, Sigma-Aldrich, from bovine skin) was dissolved in 100 ml of distilled water, while stirring at 60 °C in an oil bath. After the clear solution was formed, the sodium nitrate and ammonium niobate oxalate solutions were added and the mixture stirred continuously at 80 °C. After approximately 4 h, a viscous gel was formed, which was transferred to an alumina crucible and heated at 600 °C for 12 h. The resulting powder was then sintered at 850 °C for 5 min at a pressure of 60 MPa using SPS. SPS processed samples were subsequently annealed at 600 and 800 °C for 20 h, for nano- and sub-micron sized ceramics, respectively, to remove residual carbon arising from the carbon foil. Pellet densities were measured by the Archimedes method.

The morphology of gold coated fractured cross-sections of pelletized samples was examined using scanning electron microscopy (FEI Inspect F SEM), with an incident beam generated at 20 kV. Energy-dispersive X-ray spectroscopy (EDS) was used to examine the elemental ratio in the carbon coated ceramics. For X-ray powder diffraction and thermal analysis, pellets were crushed and ground into fine powders. XRD data were collected on a PANalytical X′Pert Pro diffractometer, fitted with an X′Celerator detector, using Ni filtered Cu-Kα radiation (λ = 1.5418 Å). Data were collected at room temperature in flat plate θ/θ geometry over the 2θ range 5-120°, with a step width of 0.0334° and an effective count time 50 s per step. Data were modeled by Rietveld analysis using the GSAS suite of programmes [33]. Structure refinement was carried out in the orthorhombic space groups Pbma and P2₁ma using the models of Xu et al. [34] and Johnston et al. [25], respectively. To examine the possibility of Na₂O loss during synthesis, free refinement of the Na site occupancy in the Rietveld analysis was carried out. In all cases the Na site occupancy refined to 1.0 within estimated standard deviation and in the final refinements these were fixed at the stoichiometric value. Differential scanning calorimetry (DSC 25. TA instruments, Asse, Belgium) was used to measure the thermal properties of the studied compositions. The
powder was heated from 20 °C to 400 °C at a heating rate of 2 °C min⁻¹, held for 5 min. and then cooled to 20 °C at a cooling rate of 2 °C min⁻¹.

For electrical measurements, pellets were ground and polished into blocks of approximate dimensions 3 mm × 3 mm × 0.25 mm and the two largest surfaces coated with silver paste (Gwent Electronic Materials Ltd. Pontypool, U.K.). The samples were heated to 300 °C to decompose the paste. The dielectric permittivity and loss were measured as a function of temperature using an Agilent 4284A LCR meter, over the temperature range 25 °C to 550 °C. I-E and P-E loops were measured at room temperature using a ferroelectric hysteresis measurement tester (NPL, UK). The electric voltage was applied in a triangular waveform [35]. A quasi-static ZJ-3B \( d_{33} \) meter (Institute of Acoustics Academia Sinica, China) was used to measure the piezoelectric coefficient \( (d_{33}) \) of samples.

3. Results and Discussion

The morphology of the studied ceramics is shown in Fig. S1. The average grain sizes were ca. 300 nm, 750 nm and 1.5 μm for nano-, sub-micron and micron sized NaNbO₃ ceramics, respectively. For the nano-sized sample, smaller (ca. 50 nm) sub-grains are seen on the surface of the main grains (Fig. S1a), as seen in previous studies [36,37]. The densities of the nano-, sub-micron and micron grain sized ceramics were found to be 4.440 g cm⁻¹, 4.515 g cm⁻¹ and 4.342 g cm⁻¹, respectively, corresponding to 97%, 99% and 95% of the respective theoretical densities. EDS analysis (Fig. S2 and Table S1) confirms the expected stochiometry in all samples, with a constant Na/Nb ratio and no evidence of significant oxide ion vacancy concentration. The results are consistent with minimal volatilization of Na₂O and minimal reduction of Nb⁵⁺.

The X-ray powder diffraction (XRD) data for the crushed pellets were fitted using two models, the non-polar Pbma model and the polar \( P2_1ma \) model. The fitted diffraction profiles for these two models are presented in Fig. S3 and Fig. S4, respectively, with the results summarized in Table S1. Details of the fits to the diffraction profiles are shown in Fig. 1. Bragg peaks corresponding to (221) and (122) reflections in Pbma or (211) and (112) reflections in \( P2_1ma \) between 38° and 39° \( \theta \) were well fitted regardless of the space group. The \( P2_1ma \) space group is a sub-group of Pbma in which the \( b \)-axis length is halved and therefore these reflections appear in both space groups. In contrast, clear differences are seen in the patterns between 36° and 37° \( \theta \). The (230) peak at ca. 36.9° \( \theta \) is unique to the Pbma supercell and allows
for a clear distinction between these two structures. As indicated by the R-factors, Fig. 1 shows that the \textit{Pbma} model better fits the data for micron grain sized NaNbO$_3$, while the \textit{P2$_1$ma} model better fits the data for nano-grain sized NaNbO$_3$. In the case of the sub-micron grain sized sample, while comparison of R-factors revealed no preference in the space group, the fit in the region shown in Fig. 1 for the two models suggests a mixture of the two phases. This may be interpreted as traces of the polar phase in a matrix of the non-polar phase.

The differential scanning calorimetry (DSC) thermograms for the three studied samples are shown in Fig. S5. Endothermic peaks were observed on heating at ca. 315 °C, 325 °C and 360 °C for nano-, sub-micron and micron grain sized NaNbO$_3$ samples, respectively. The temperatures of the corresponding exothermic peaks are lower than those of the endothermic peaks and are associated with a first order phase transition [17]. This transition occurs at a higher temperature for the larger grain sized NaNbO$_3$ sample. This indicates that there is a lower polarization in the smaller grain sized ceramics, which leads to the lower phase transition temperatures. For micron grain-sized NaNbO$_3$, a step in the DSC thermogram is observed at ca. 85 °C on heating, with a corresponding change in slope at the same temperature during cooling. Although no similar steps or changes in slope are seen on heating in the thermograms of nano- and sub-micron grain sized samples, there is a small change in slope on cooling at this temperature for these samples, but less pronounced than in the micron grain sized sample. Such features are typically associated with second order transitions.

Dielectric permittivity ($\varepsilon'$) and loss (tan $\delta$) were measured at selected frequencies on cooling from 600 °C to avoid moisture effects (Fig. 2). Dielectric loss was found to be more significant in the nano- and sub-micron grain sized ceramics. This can be attributed to a small degree of reduction in the ceramics during SPS processing, which introduces low levels of oxide ion vacancies. These remain, despite subsequent annealing of the sintered ceramics, but the levels are lower than the detection limit of EDS. A clear peak in dielectric permittivity at ca. 300 °C is observed for all samples. This peak has been attributed to the phase transition from the AFE R-phase, in space group \textit{Pnmm} above 300 °C, to the AFE P-phase, in space group \textit{Pbma} [17]. The fact that the \textit{Pbma} phase is not observed in the nano-grain sized sample, but the dielectric permittivity peak at 300 °C is still seen, suggests that this transition is more complex. It is also noteworthy that this peak broadens with decreasing grain size, indicating that
the phase transition occurs over an increasing temperature range, consistent with a decrease in crystallographic order.

The results suggest that the reported $Pnmm \rightarrow Pbma$ phase transition on cooling actually occurs via the $P2_1ma$ phase, i.e.

$$Pnmm \rightarrow P2_1ma \rightarrow Pbma$$

The reduction in grain size has the effect of suppressing the second phase transition. Thus, in the nano-grain sized sample the polar $P2_1ma$ phase is observed at room temperature [31] and the $Pnmm \rightarrow P2_1ma$ transition occurs over a wide temperature range, leading to a broadening of the dielectric permittivity peak. This type of phase behavior has been noted before in BaTiO$_3$, where a reduction of grain size leads to suppression of the cubic to tetragonal phase transition on cooling [6]. The $Pnmm$ to $P2_1ma$ phase transition involves a tilting of the NbO$_6$ octahedra and a change in the tilting system from $a'b'a'$ to $a'b'a$, while the $P2_1ma$ to $Pbma$ transition involves a doubling of the unit cell along the $b$-axis, with the layers in the top half and bottom half having opposing tilt directions (Fig. 3).

Inspection of the dielectric permittivity plot for micron grain size NaNbO$_3$ from 150 $^\circ$C to 100 $^\circ$C (Fig. 2c), reveals an anomaly not present in the plots for the other samples. This anomaly has also been found by other researchers, but its origin is still under debate [38]. Raman spectroscopic and synchrotron X-ray diffraction studies concluded that the so called P-phase was actually three different phases, each with a different stability range, i.e. a monoclinic phase from 23 $^\circ$C to 137 $^\circ$C, an incommensurate phase (INC) from 137 $^\circ$C to 187 $^\circ$C and an orthorhombic phase from 187 $^\circ$C to 360 $^\circ$C [23]. An in situ TEM study confirmed the existence of the INC phase in NaNbO$_3$ at 165 $^\circ$C [39]. However, Koruza et al. reported that the observed dielectric anomaly in NaNbO$_3$ at around 150 $^\circ$C was associated with relaxor behavior and was caused by ferroelectric nano-regions embedded in an antiferroelectric matrix, rather than a discrete phase transition [40]. Indeed, later neutron diffraction studies by Mishra et al. failed to identify any phase transitions in the P-phase region [24].

The present results indicate that the $P2_1ma$ phase is an intermediate phase between the R ($Pnmm$) and P ($Pbma$) phases. Therefore, it is possible that the anomaly seen in micron grain size NaNbO$_3$ from 150 $^\circ$C to 100 $^\circ$C (Fig. 2c) is associated with a phase transition from the $P2_1ma$ phase to the $Pbma$ phase. In order to investigate this anomaly, dielectric permittivity measurements were carried out on a poled sample of micron grain sized NaNbO$_3$ on heating and cooling (Fig. 4). The peak
associated with the anomaly was found to be absent on heating, but present on cooling. This may be explained by considering the effect of poling on the sample. The high field used in poling the sample likely induces the transition from the $Pbma$ to the $P2_1ma$ phase at room temperature, so that on heating if indeed the anomaly is associated with the $P2_1ma$ to $Pbma$ transition, it would be expected to be absent. On heating the poled sample above $300 \ ^\circ C$ to the R-phase region, depoling occurs and on subsequent cooling the anomaly reappears. In contrast, with smaller grain size NaNbO$_3$ samples, the anomaly is always absent both on heating and cooling. This suggests that the $Pbma$ phase is only a minor phase or not formed at all in small grain size NaNbO$_3$ samples.

On cooling, NaNbO$_3$ samples from $300 \ ^\circ C$, they undergo the $Pnmm \rightarrow P2_1ma$ phase transition, i.e. from a non-polar to a polar structure. This transition involves the growth of polar regions. The polar region surface would be charged as a result of this polarization and the resulting field is known as the depolarizing field, $E_d$ [5]. $E_d$ therefore represents a positive contribution to the free energy of the $P2_1ma$ phase. For nano-grain sized NaNbO$_3$, the size of the polar regions is constrained by the small grain size and consequently for a single polar region $E_d$ is small. This means, that in small grain sized samples, the $P2_1ma$ phase has a lower free energy than the $Pbma$ phase and there is no significant energy to be gained in ordering to form the $Pbma$ phase. Hence the $P2_1ma$ phase is stabilized at room temperature. On the other hand, in large grain sized samples, the growth of the polar region at the $Pnmm \rightarrow P2_1ma$ phase transition is no longer limited by the grain size and polar regions continue to grow to give larger regions, with larger $E_d$. This makes the $P2_1ma$ phase less stable with respect to the $Pbma$ phase. Minimization of $E_d$ typically involves polar regions splitting into neighboring regions with antiparallel polarization [41]. This process involves the ordering of adjacent dipoles and eventually leads to the formation of the AFE $Pbma$ phase. Thus in large grain sized samples, the ordering process is energetically favored as the sample is cooled and the $P2_1ma \rightarrow Pbma$ phase transition is observed.

Low-field polarization-electric field (P-E) and current-electric field (I-E) loops for the studied samples are shown in Fig. 5. All samples showed tilted I-E loops associated with a leakage current. Only micron grain sized NaNbO$_3$ shows current peaks at around $\pm 1 \ kV \ mm^{-1}$. These might be associated with a field induced phase transition e.g. from the $Pbma$ phase to the $P2_1ma$ phase or with a coercive field, $E_c$ arising from some residual $P2_1ma$ phase within the predominant $Pbma$ matrix. For smaller grain sized samples, where the polar phase was evident in X-ray diffraction data, no current peaks are seen at these fields, which suggests that the applied electric field was
insufficient to facilitate domain switching. The measured, $d_{33}$ value of the micron grain sized sample post experiment was $0.6 \pm 0.1$ pC N$^{-1}$, confirming a small remnant polarization after application of an applied field of 6 kV mm$^{-1}$. Those for the nano- and sub-micron grain sized samples were 15.4 and 2.2 pC N$^{-1}$, respectively.

P-E/I-E loops measured under high electric fields are shown in Fig. 6. Two current peaks are observed in the I-E loops for the sub-micron and nano-grain sized samples and can be attributed to domain switching of the FE phase. It is noticeable that the coercive field of the sub-micron grain sized sample is lower than that of the nano-grain sized sample (ca. 6 kV mm$^{-1}$ and ca. 8 kV mm$^{-1}$, respectively). The higher grain boundary concentration in nano-grain sized NaNbO$_3$ increases the so called “pinning effect” i.e. they serve as barriers to domain switching and consequently a high coercive field is required for domain switching to occur [42]. Four current peaks are observed in the I-E loop of the micron grain sized sample (Fig. 6c). The lower field peak at ca. 4.5 kV mm$^{-1}$ is attributed to the transition from the FE $P2_1ma$ phase to the AFE $Pbma$ phase, while the second peak at ca. 7 kV mm$^{-1}$ is associated with the reverse transition. The values of the applied fields at these transitions are denoted $E_{AFE}$ and $E_{FE}$, respectively. Thus at points 1 and 3 in Fig. 6c the sample is in the FE phase, while at point 2, it is in the AFE state. This field induced AFE phase was also observed in NaNbO$_3$ based ceramics and confirmed by XRD measurements [43].

Fig. 7 shows fitted X-ray diffraction patterns of virgin and poled (at 14 kV mm$^{-1}$) micron sized NaNbO$_3$ ceramics, modeled using the $Pbma$ and $P2_1ma$ structures, with those for sub-micron and nano-grain sized ceramics given in Figs. S6 and S7, respectively. There is a clear difference observed in the 2$\theta$ range 35-39° between the virgin and poled samples in the micron grain sized ceramic. For this sample, the diffraction pattern of virgin NaNbO$_3$ ceramic is clearly better fitted using the non-polar $Pbma$ structure, while after poling both models fit equally well and cannot be distinguished. However, the pattern of the poled sample in this 2$\theta$ range closely resembles that of the nano-grain sized powder sample shown in Fig. 1, which was dominated by the polar phase. This suggests that high electric field induces a phase transition from non-polar to polar structures in micron grain sized NaNbO$_3$ ceramics. Similar behaviour is seen in the sub-micron grain sized ceramic (Fig. S6), while in the nano-grain sized ceramic the polar structure appears to be maintained throughout.

In order to further investigate the anomaly in the dielectric permittivity seen in micron grain sized NaNbO$_3$, variable temperature P-E/I-E measurements were performed at low electric fields (Fig. S8). With increasing temperature, the current peaks shift to lower electric field. As discussed above, these current peaks are attributed to domain
switching in local FE regions in a non-polar matrix. In addition, the magnitude of the current peaks decreases with increasing temperature and the peaks disappear at 150 ºC. This suggests that the extent of the polar regions diminishes with increasing temperature, leaving only the non-polar AFE matrix, i.e. the pure Pbma phase. Indeed, further increase in temperature up to 200 ºC leads to a normal FE hysteresis loop at high field, with only 2 current peaks in the I-E loop (Fig. 8), compared to the 4 current peaks seen at room temperature (Fig. 6c). The results are consistent with the dielectric anomaly seen at ca. 150 ºC as being due to the Pbma ↔ P2₁ma transition.

5. Conclusions

Sodium niobate ceramics with different grain sizes (300 nm to 1.4 µm) have been successfully prepared using solid state and sol-gel methods, with conventional sintering and SPS. For micron grain sized ceramics, samples were predominantly in the AFE P-phase (space group Pbma), while nano-grain sized samples exhibited a structure with P2₁ma symmetry that showed FE behaviour. Sub-micron grain sized samples exhibited a mixture of both phases. An anomaly seen in the dielectric permittivity of micron grain-sized NaNbO₃ is attributed to the transition between AFE and FE phases. The transition from FE to AFE phases involves ordering of dipoles to generate an ordered structure with opposing tilt directions, resulting in doubling of the unit cell. The results of this work suggest that the FE P2₁ma phase is always formed directly from the R-phase at 300 ºC on cooling and that the previously reported R ↔ P phase transition does not occur directly, but proceeds via the P2₁ma phase, with the P2₁ma to Pbma (FE to AFE) transition occurring at around 150 ºC. The work has shown that the growth of FE domains in small grain sized ceramics is suppressed, making the FE to AFE transition less energetically favourable, allowing for the FE P2₁ma phase to be stabilized to room temperature. The results indicate that careful control of microstructure through processing conditions can allow for tailoring of dielectric behaviour in ceramics, allowing for its use in the design and manufacture of a variety of new electronic devices.

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Fig. 1. Detail of the fits to X-ray diffraction profiles for NaNbO$_3$ samples of different grain size using the $P2_1ma$ and $Pbma$ models.
Fig. 2. Thermal variation of dielectric relative permittivity and loss on cooling for (a) nano (b) sub-micron and (c) micron grain sized NaNbO$_3$.
Fig. 3. Crystal structures of sodium niobate in space groups (a) $Pnmm$, (b) $P2_1ma$ and (c) $Pbma$, with the unit cells indicated by dashed lines.

Fig. 4. Temperature dependence of dielectric permittivity and loss for poled micron grain sized NaNbO$_3$. 
Fig. 5. P-E/I-E loops of NaNbO$_3$ samples measured under low electric field at 10 Hz, showing data for (a) nano-, (b) sub-micron and (c) micron grain sized samples.

Fig. 6. P-E/I-E loops for NaNbO$_3$ samples measured at high electric field, showing data for (a) nano, (b) sub-micron and (c) micron grain sized samples.

Fig. 7. Detail of fitted X-ray diffraction profiles of unpoled and poled micron sized NaNbO$_3$ ceramics.
Fig. 8. I-E/P-E loops for a micron grain sized NaNbO$_3$ ceramic measured under (a) low electric field and (b) high electric field.